

# Non-Maxwellian analysis of *IRIS* TR lines

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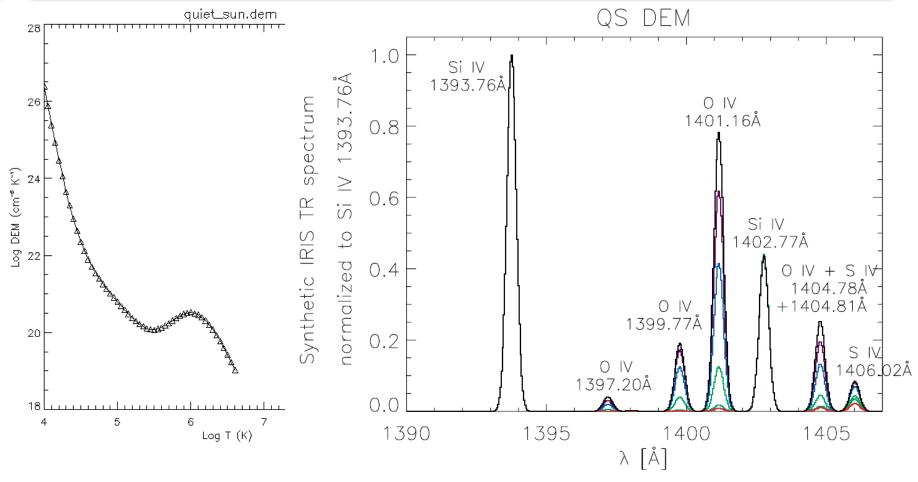
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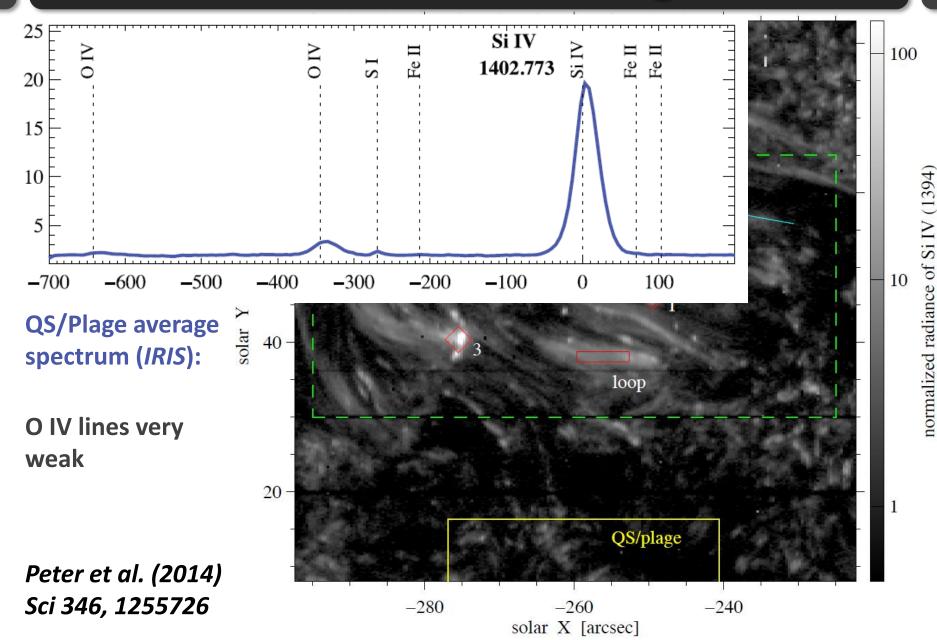
### Synthetic IRIS TR spectrum



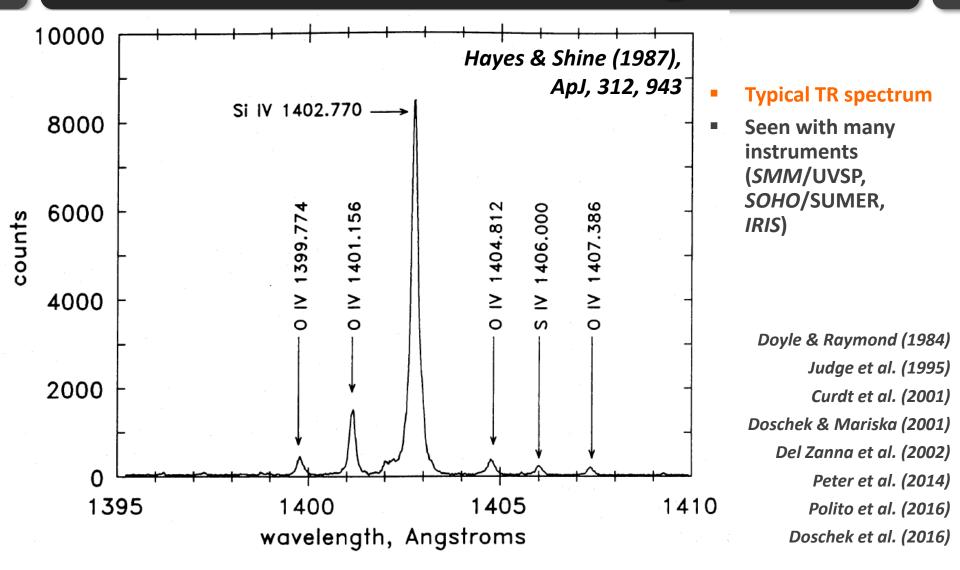
Dudík et al. (2014), ApJ 780, L12

- Predicted IRIS FUV2 spectrum for a typical quiet Sun DEM:
   O IV 1401.2 Å line stronger than the Si IV 1402.8 Å
- For AR, with steeper DEM slope, O IV > Si IV also

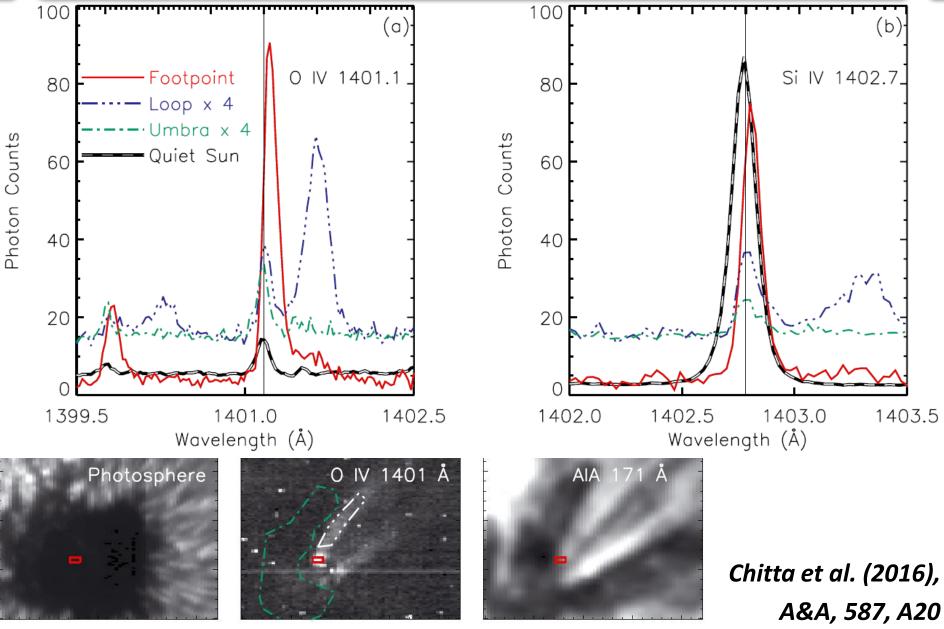
### **TR Lines: Challenges**



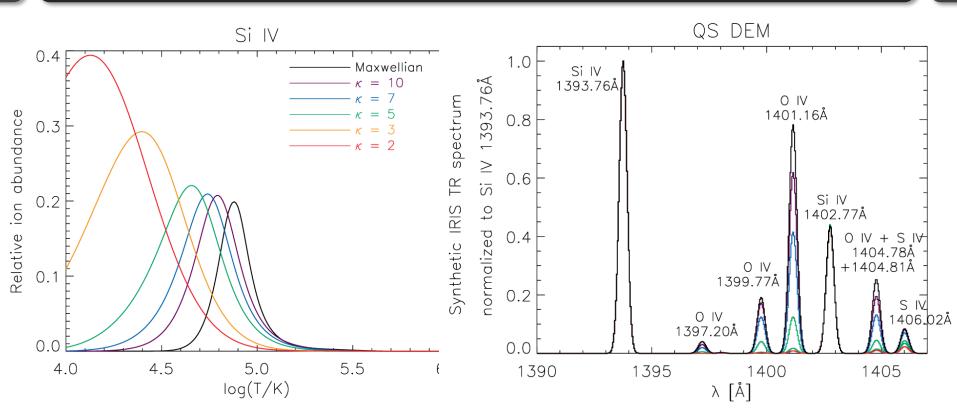
#### **TR Lines: Challenges**



# **OIV > SiIV ?:** Single Solar Case



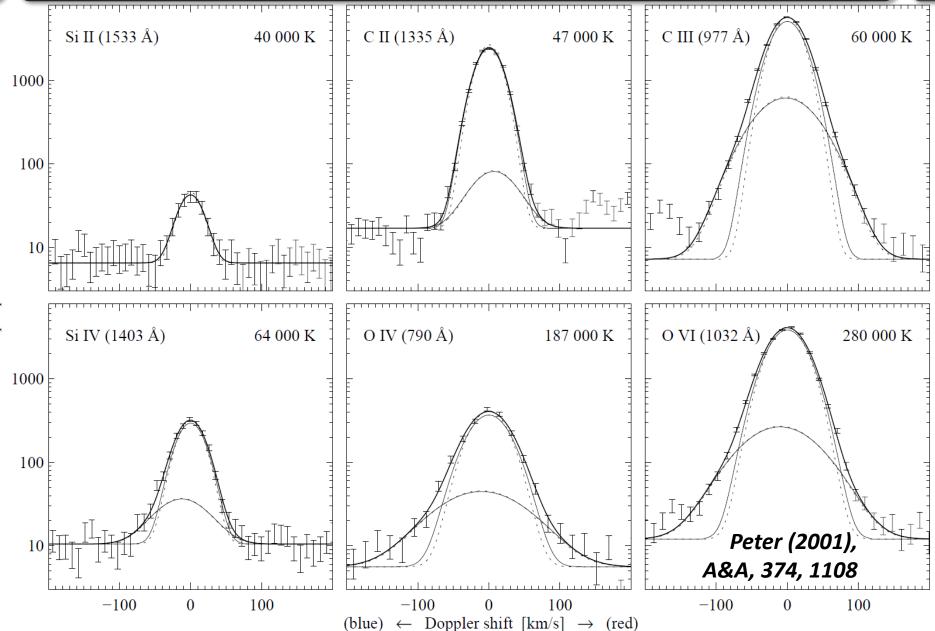
# The *k*-distributions and TR lines



Dzifčáková & Dudík (2013), ApJS, 206, 6 Dudík et al. (2014), ApJL, 780, L12 Dzifčáková et al. (2017), A&A, in press

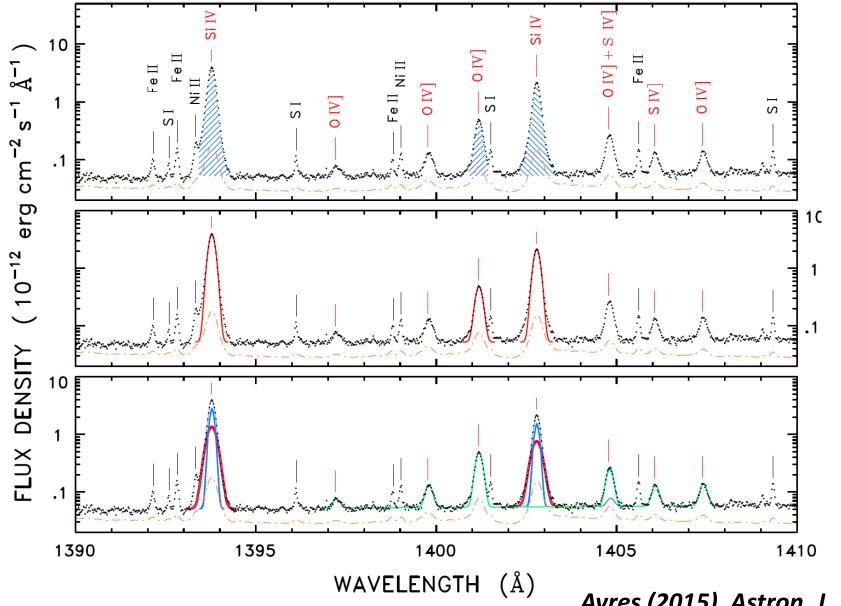
- For TR lines, ion abundance peaks are shifted to lower T
- High-energy tail: ionization rate enhanced by orders of magnitude
- Recombination enhanced by a factor of < 2</p>

#### **Non-Gaussian Line Profiles**



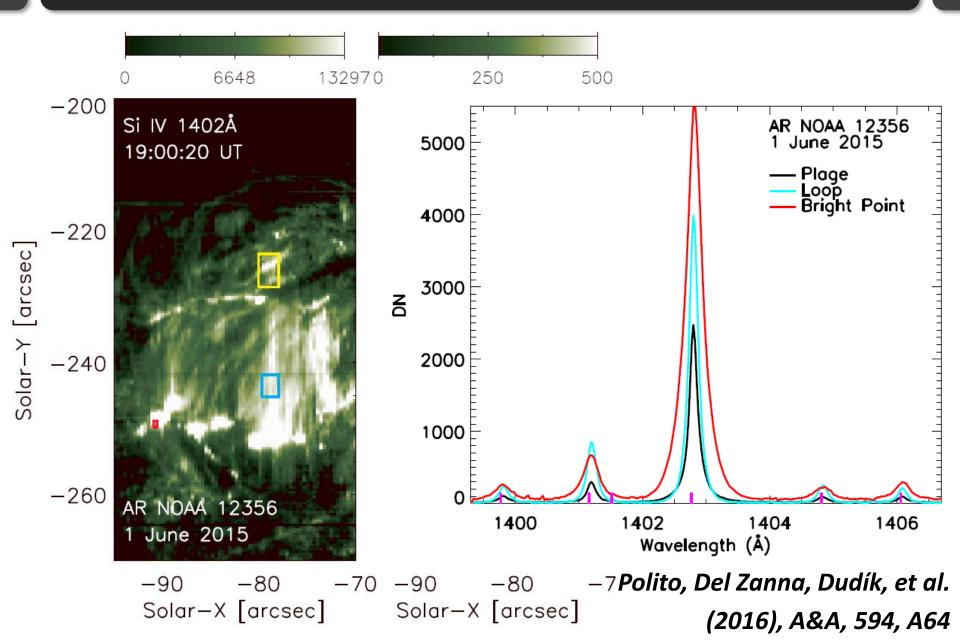
counts per pixel in 115 s

#### α Centauri A+B

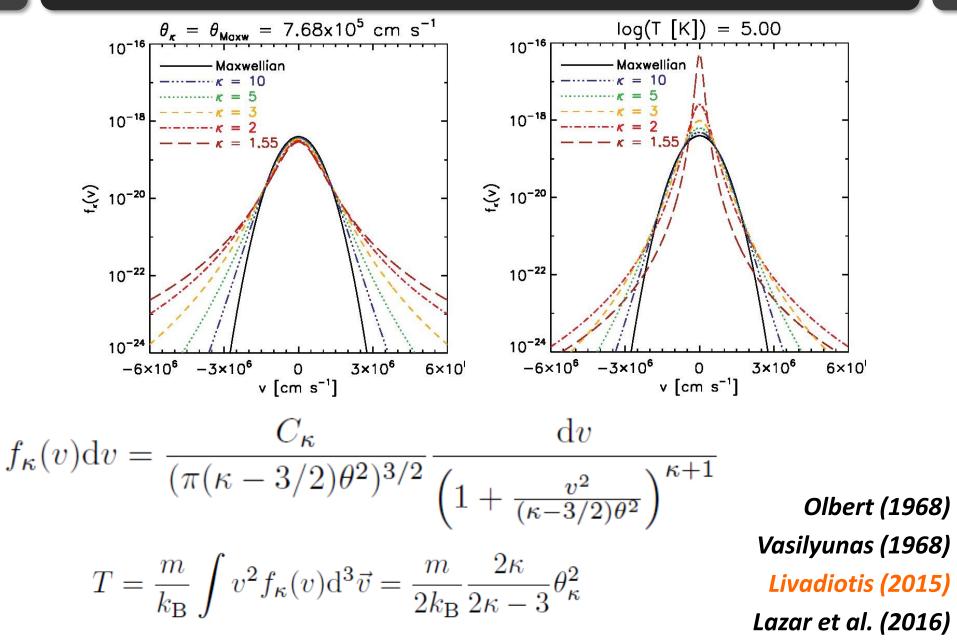


Ayres (2015), Astron. J., 149, 58

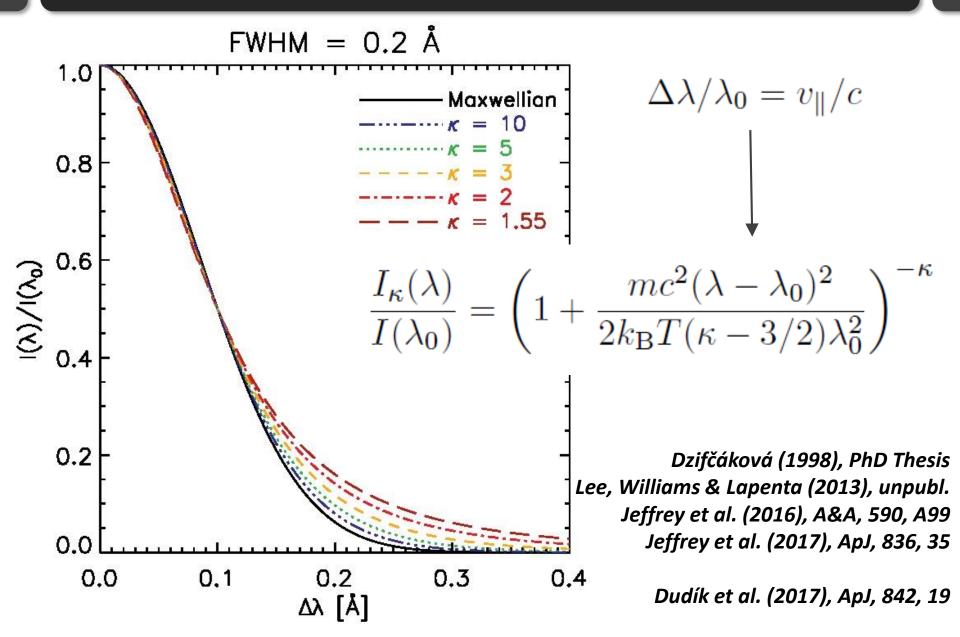
#### **Non-Gaussian Line Profiles:** *IRIS*



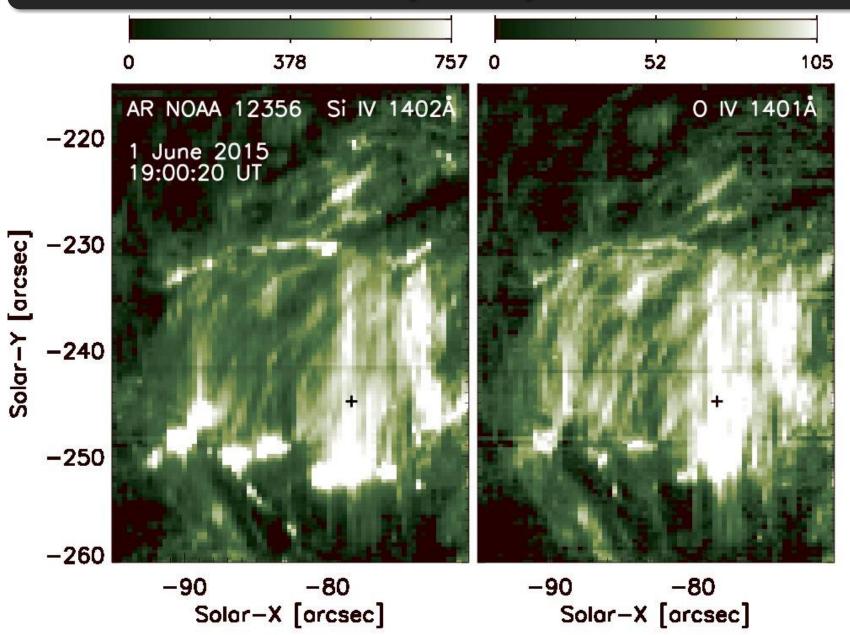
#### The *k*-distributions



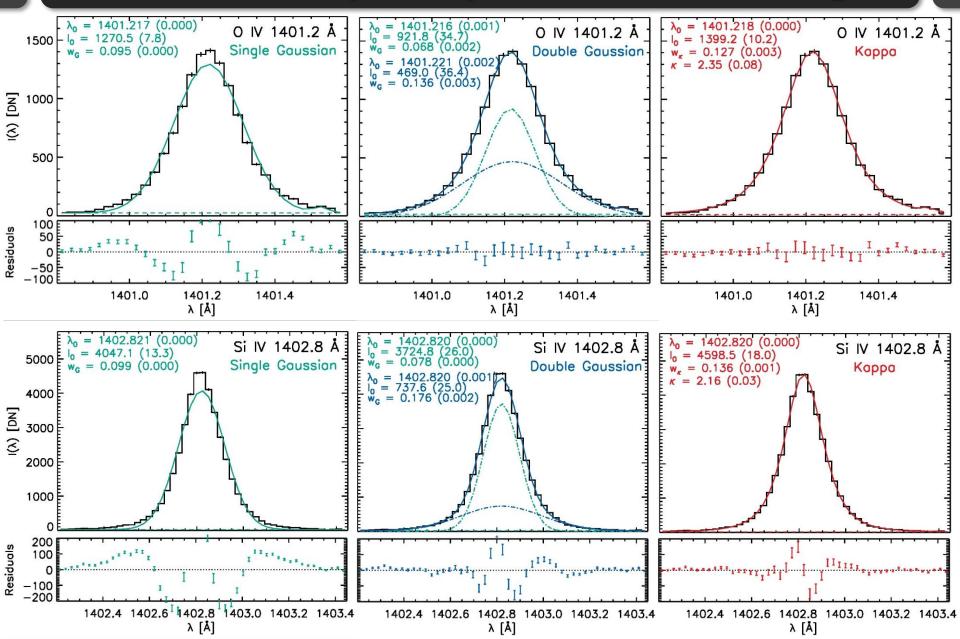
#### *k*-Distributions and Line Profiles



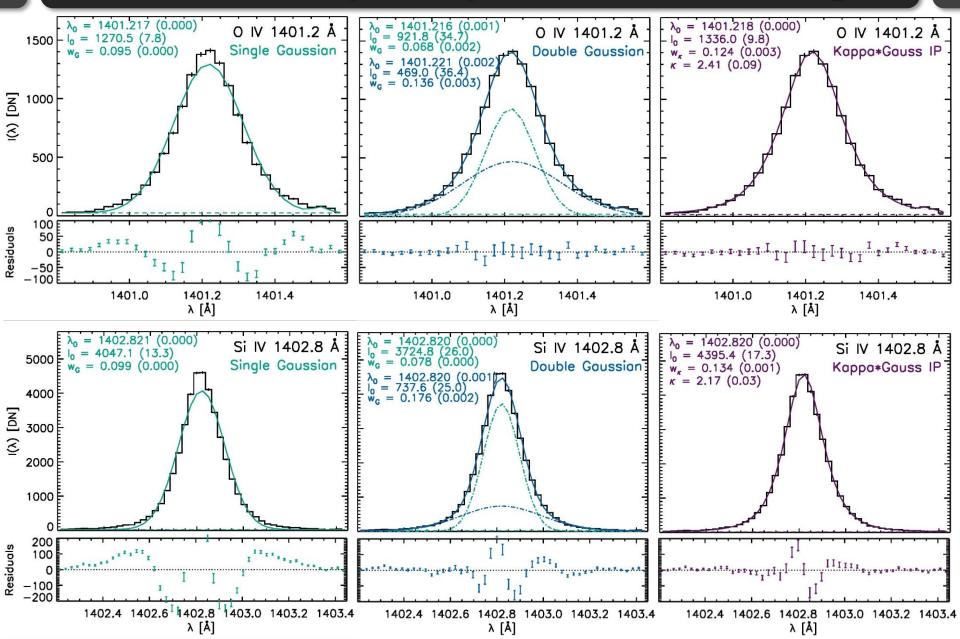
### **IRIS Example Spectrum**



#### **IRIS** Example Spectrum: Fitting



#### **IRIS Example Spectrum: Fitting**



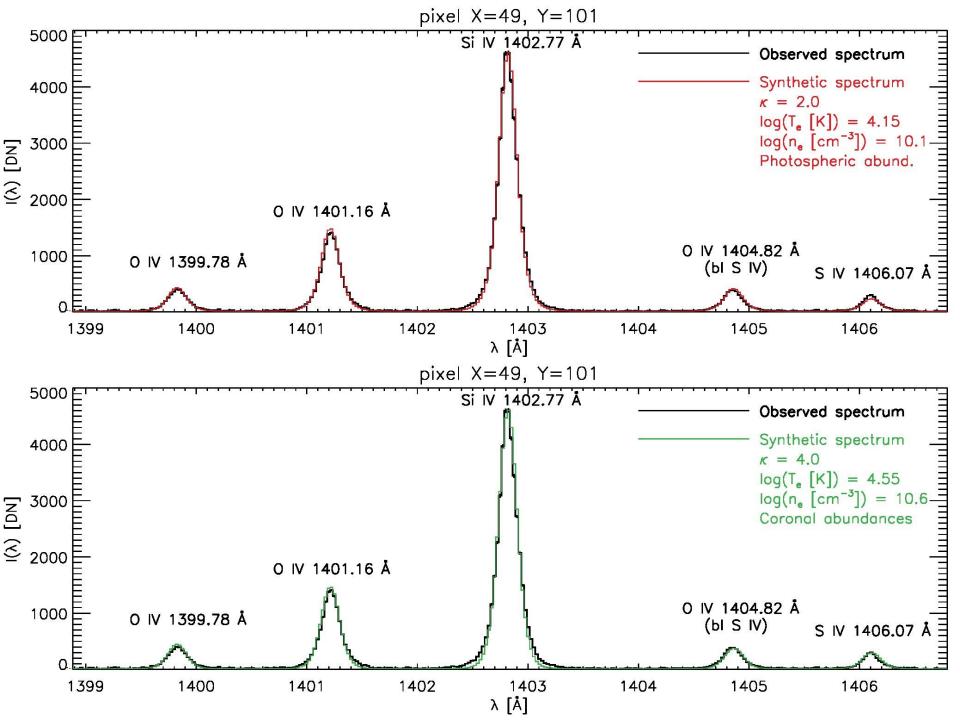
# **IRIS Example Spectrum: Fitting**

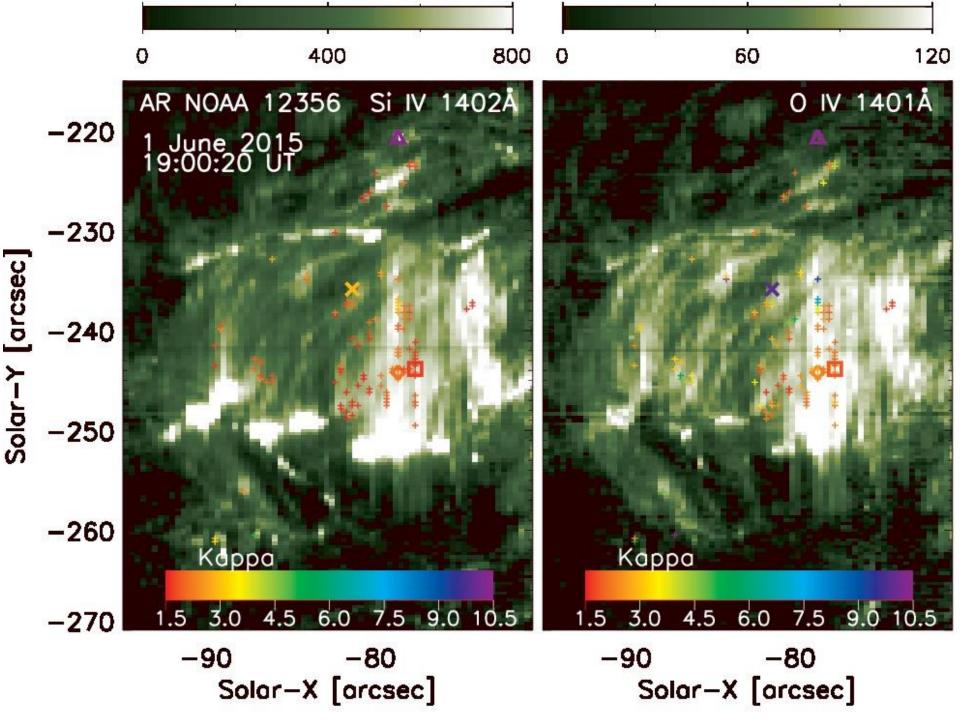
Line	$\lambda_0 \; [{ m \AA}]$	$I_0$ [DN]	$w_{\kappa}$ [Å]	$\kappa$	$\mathrm{FWHM}_{\kappa}$ [Å]	$T_{\rm i} \; [{\rm MK}]$
O IV 1399.78 Å	$1399.831 \pm 0.001$	$385 \pm 6$	$0.143 \pm 0.010$	$2.16 \pm 0.17$	$0.20 \pm 0.08$	$1.81 \pm 0.26$
O IV 1401.16 Å	$1401.218 \pm 0.000$	$1399\pm10$	$0.127 \pm 0.003$	$2.35 \pm 0.08$	$0.20\pm0.05$	$1.43\pm0.06$
Si IV 1402.77 Å	$1402.820 \pm 0.000$	$4598 \pm 18$	$0.136 \pm 0.001$	$2.16 \pm 0.03$	$0.19\pm0.02$	$2.86\pm0.06$
O IV 1404.82 Å (bl S IV)	$1404.855 \pm 0.001$	$383 \pm 6$	$0.163 \pm 0.018$	$1.90\pm0.13$	$0.19\pm0.13$	$2.35 \pm 0.52$
S IV 1406.06 Å	$1406.103 \pm 0.001$	$282\pm5$	$0.144 \pm 0.021$	$1.91\pm0.18$	$0.17\pm0.17$	$3.64 \pm 1.08$

- (Almost) consistent κ values derived from all five TR lines
- All five lines have the same FWHM
- Significant non-thermal widths

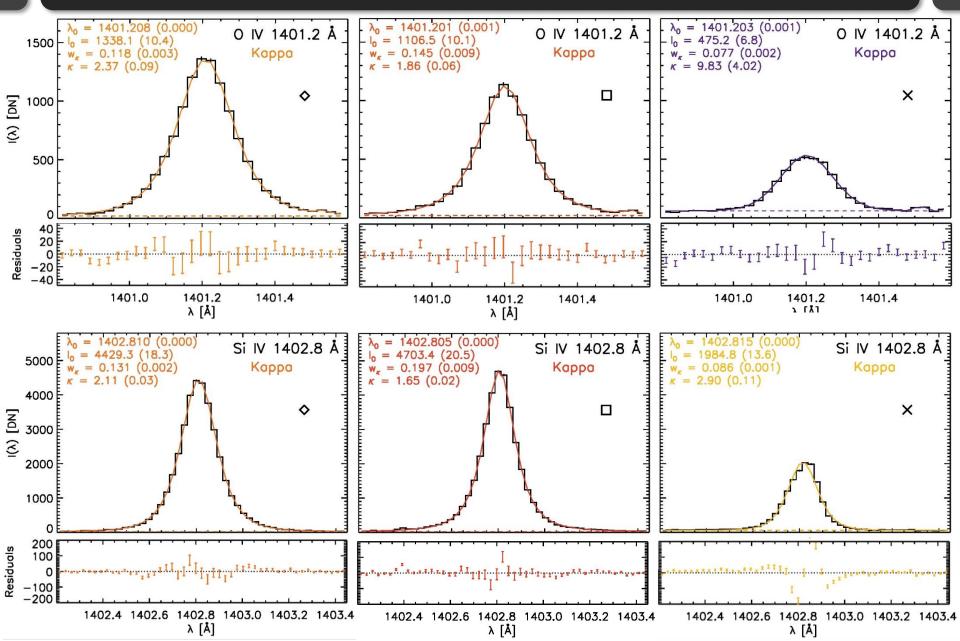
$$w_{\kappa}^2 = \frac{1}{2} \frac{\lambda_0^2}{c^2} (\theta^2 + (\theta^{(\mathrm{nth})})^2) = (w_{\kappa}^{(\mathrm{th})})^2 + (w_{\kappa}^{(\mathrm{nth})})^2$$

Line	$w_{\kappa}$ [Å]	$\log(T_{\max, Maxw} [K])$	$w_{ m Maxw}^{ m (th)}$	$w_{ m Maxw}^{ m (nth)}$	$\log(T_{\max,\kappa=2} [K])$	$w_{\kappa=2}^{(\mathrm{th})}$	$w_{\kappa=2}^{(\mathrm{nth})}$
O IV 1399.78 Å	$0.143 \pm 0.010$	5.15	0.040	0.137	4.45	0.018	0.141
O IV 1401.16 Å	$0.127 \pm 0.003$	5.15	0.040	0.121	4.45	0.018	0.126
Si IV 1402.77 Å	$0.136 \pm 0.001$	4.90	0.023	0.134	4.10	0.009	0.136
O IV 1404.82 Å (bl S IV)	$0.163 \pm 0.018$	5.15	0.040	0.158	4.45	0.018	0.162
S IV 1406.06 Å	$0.144 \pm 0.021$	5.05	0.025	0.141	4.20	0.009	0.143

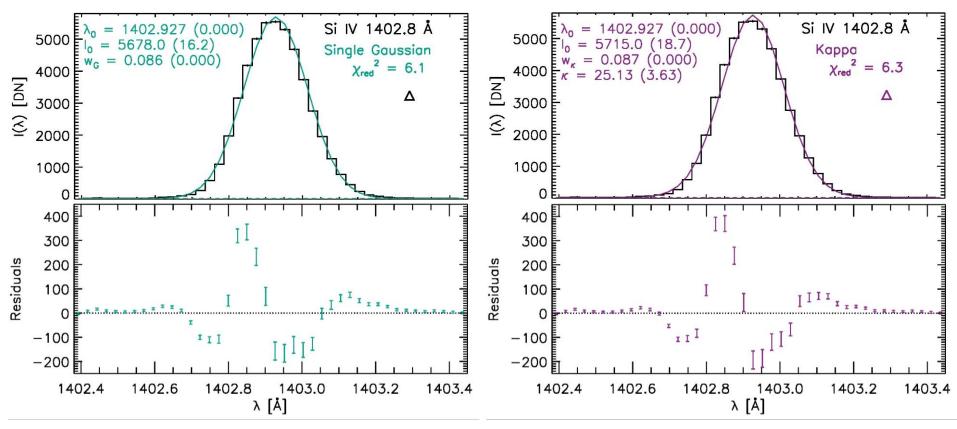




#### More cases...

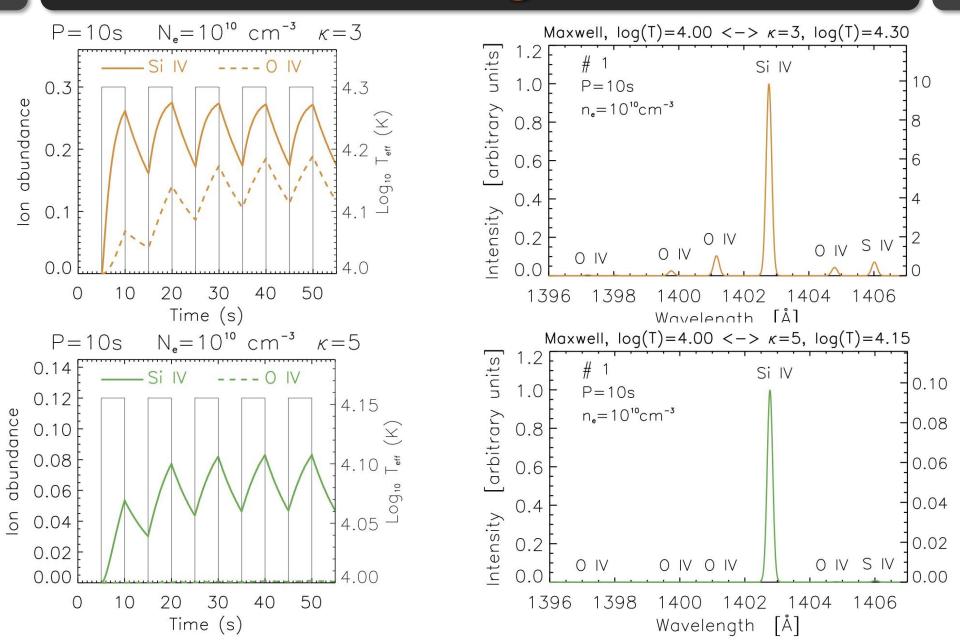


# Si IV: Case of a Gaussian Profile



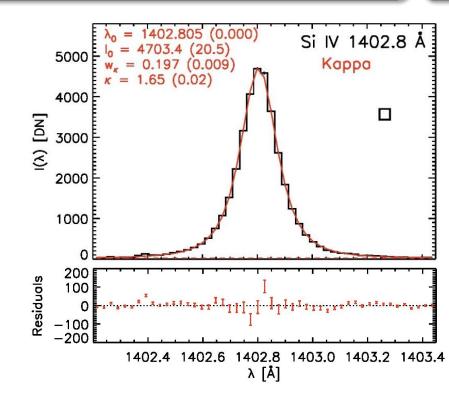
- Detection of a single, very bright Gaussian pixel
- Third brightest pixel with symmetric profiles
- The non- Gaussian profiles are not caused by instrumental effects
- Larger / asymmetric residuals: Possibly 2 Gaussian components

#### Tails too strong? : κ + NEI



### Summary

- Detected non-Gaussian, highly symmetric profiles of TR lines in 120 pixels
- Typical κ values found from profiles are κ ≈ 1.7 – 2.5
- This is not an instrumental effect
   we detected a Gaussian pixel
- Typical κ values found from fitting of relative intensities are κ ≈ 2 3 (but sensitive to abundances)
- The Si IV 1402.8 Å line is optically thin

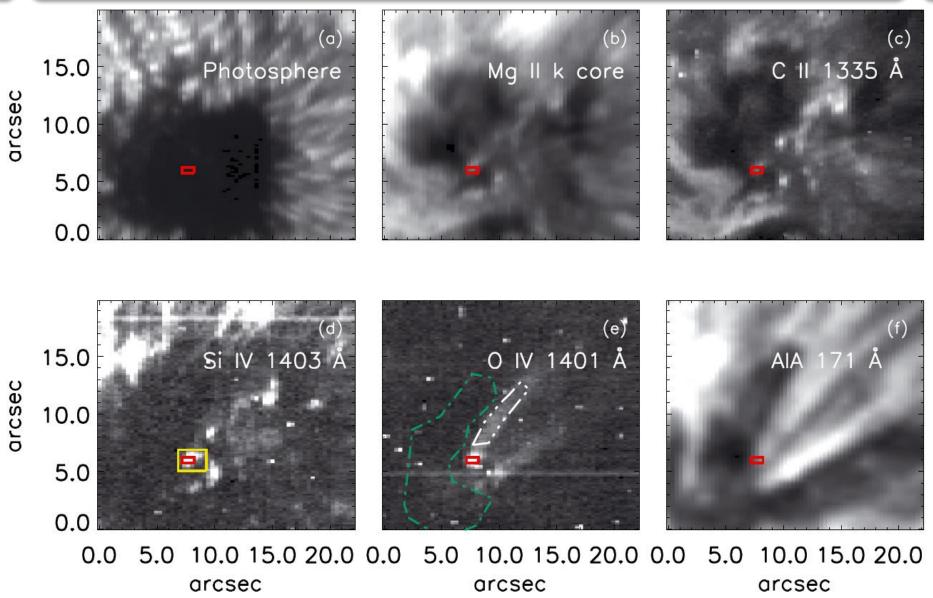


#### Dudík et al. (2017), ApJ, 842, 19

Review on non-Maxwellians and non-equilibrium ionization:

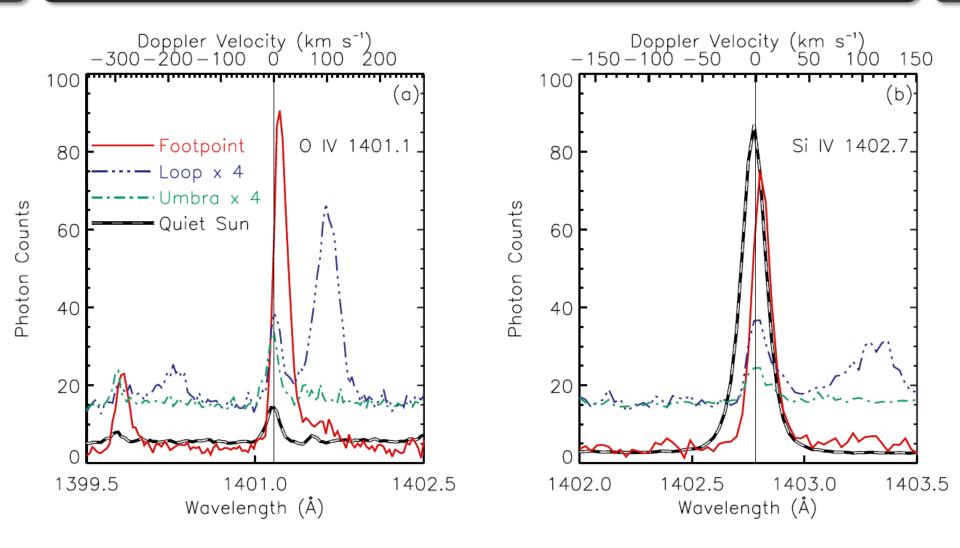
Dudík et al. (2017), Solar Phys., accepted

### **O IV** can be stronger than Si IV



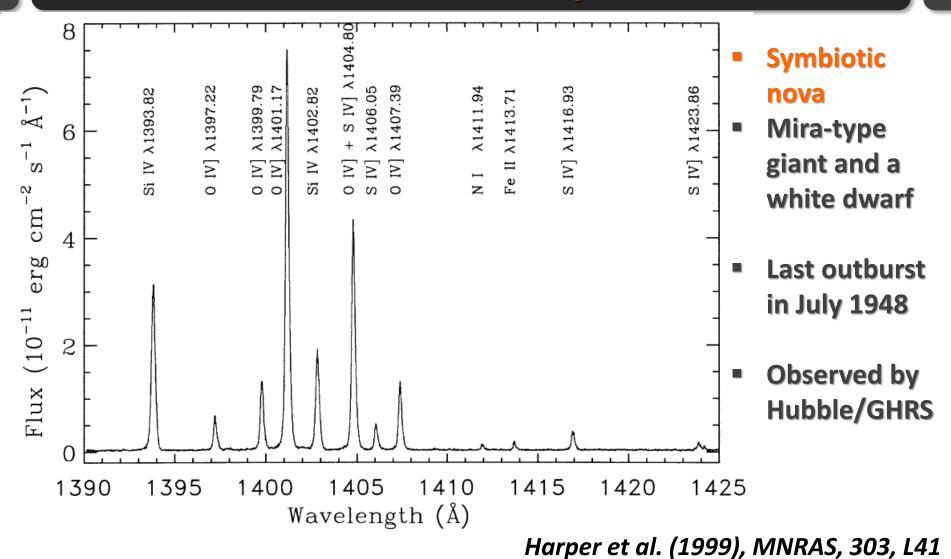
Chitta et al. (2016), A&A, 587, A20

### **O IV** can be stronger than Si IV



Chitta et al. (2016), A&A, 587, A20

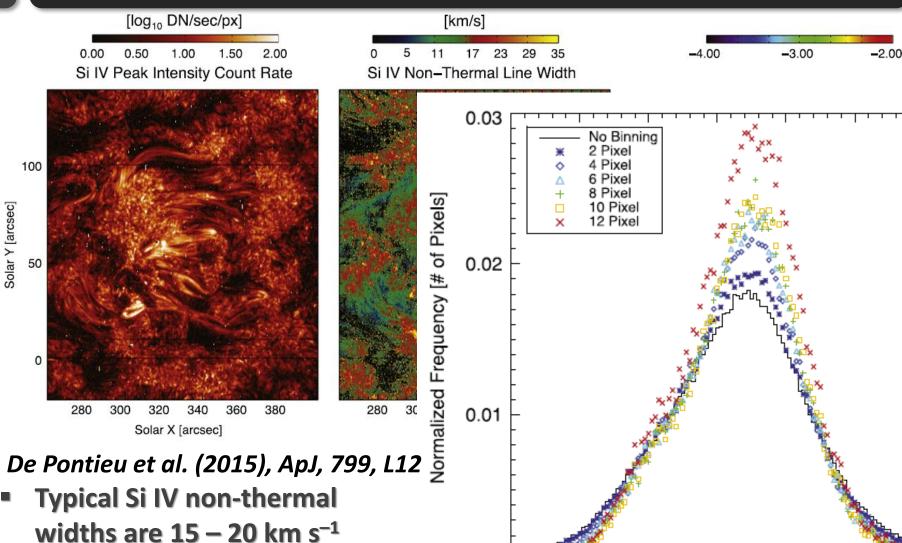
#### **Case of RR Telescopii Nebula**



See also Keenan et al. (2002), MNRAS, 337, 901

Del Zanna et al. (2002), A&A, 385, 968

# **Non-thermal widths**



0.00

0

5

10

15

Si IV 1403Å Non-Thermal Line Width [km/s]

20

25

30

Independent of spatial resolution

# **Non-Equilibrium Ionization (NEI)**

$$\frac{\partial Y_i}{\partial t} + \frac{\partial}{\partial s}(Y_i v) = n_e(I_{i-1}Y_{i-1} + R_iY_{i+1} - I_iY_i - R_{i-1}Y_i + \cdots)$$

#### e.g., Bradshaw & Mason (2003), A&A 401, 699

#### where

- $Y_i$  population of ion +*i*
- v plasma velocity along s (loop)

- $I_i$  total ionization rate of ion +*i*
- $R_i$  total recombination rate of ion

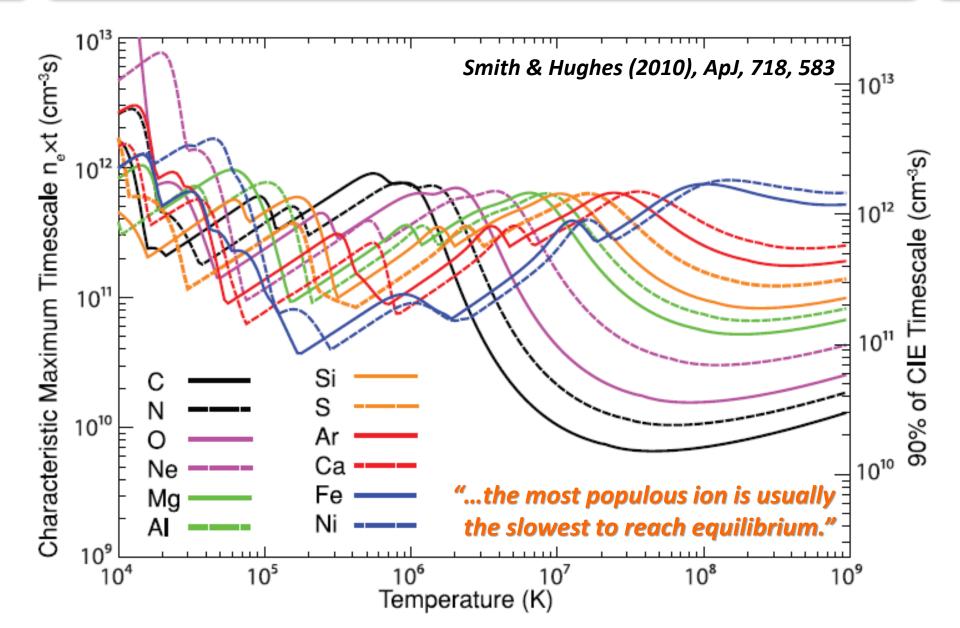
#### If v = 0:

- Coupled set of Z+1 first-order differential equations for Y<sub>i</sub>
- Can be re-cast as Z uncoupled first-order diff eqs using eigenvector basis
- Solution is a set of Z separate exponential functions
- Ionization equilibration timescale is given by the smallest eigenvalue  $\lambda_i$

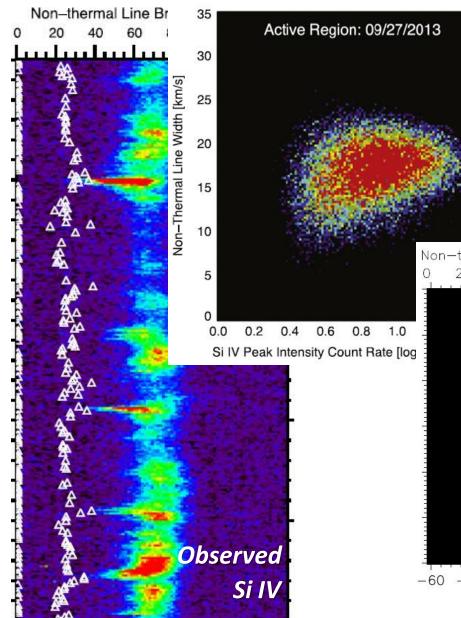
$$Y_i(t, T_e) - Y_{i,eq}(T_e) = \sum_j W_{ji}(T_e)c_j \exp\left(-n_e\lambda_j t\right)$$

Smith & Hughes (2010), ApJ, 718, 583 see also Golub et al. (1989), SoPh 122, 145; Reale & Orlando (2008), ApJ 684, 715

#### **NEI: Timescales**



# **NEI and non-thermal broadening**

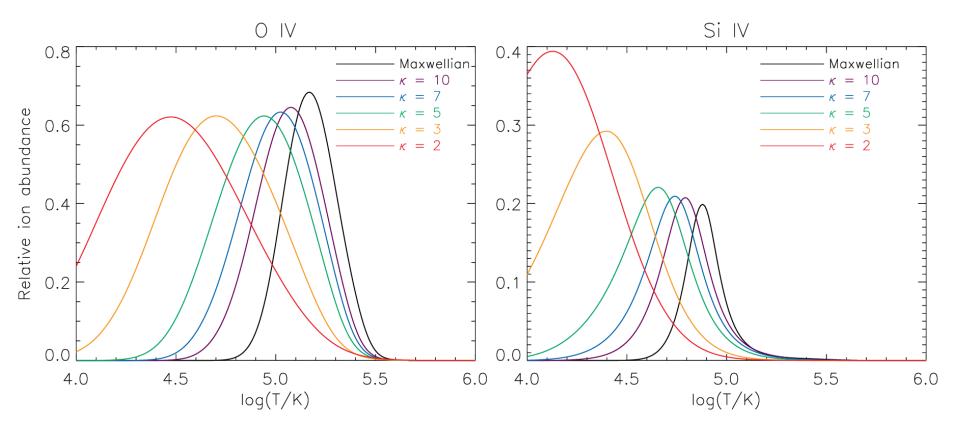


#### DePontieu et al. (2015), ApJL 799, L12

- Observed: width correlated with intensity, independent of resolution
- Slow magnetoacoustic shocks
- In simulations, NEI increases the broadening by 2 – 10 km s<sup>-1</sup> and produces a correlation

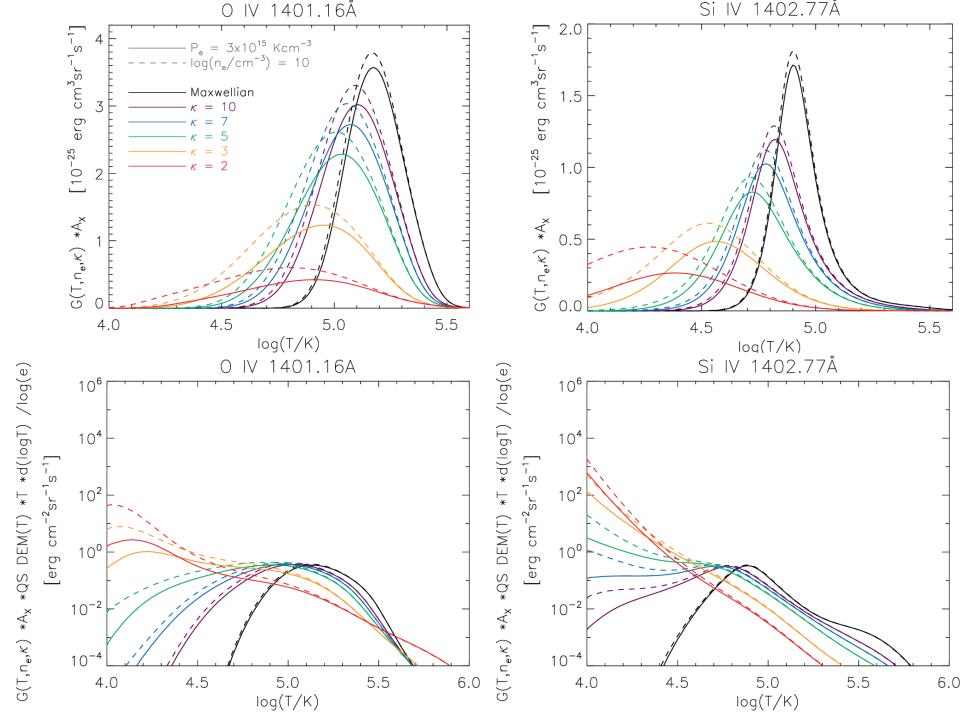
Non-thermal Line Broadening [km/s] Non-thermal Line Broadening [km/s] 8 10 12 14 6 0 2 4 6 8 10 12 14 Simulated CIE NEI -60 -40 -20 0 20 40 60 -60 -40 -20 40 0 20 60 Wavelength [km/s] Wavelength [km/s]

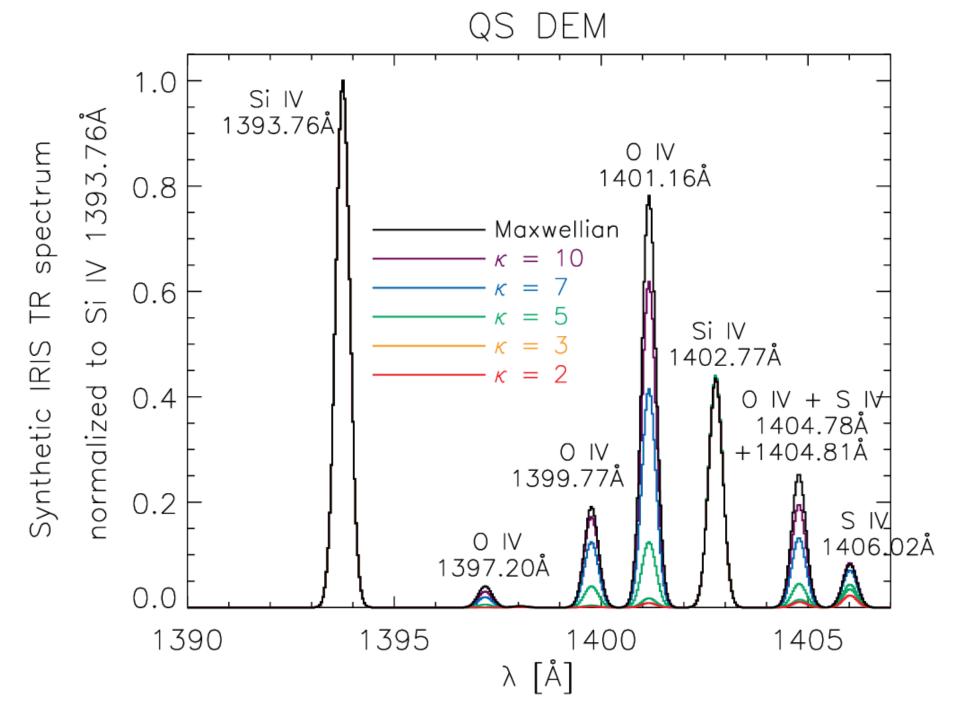
# The *k*-distributions and TR lines



Dzifčáková & Dudík (2013), ApJS, 206, 6 Dudík et al. (2014), ApJL, 780, L12

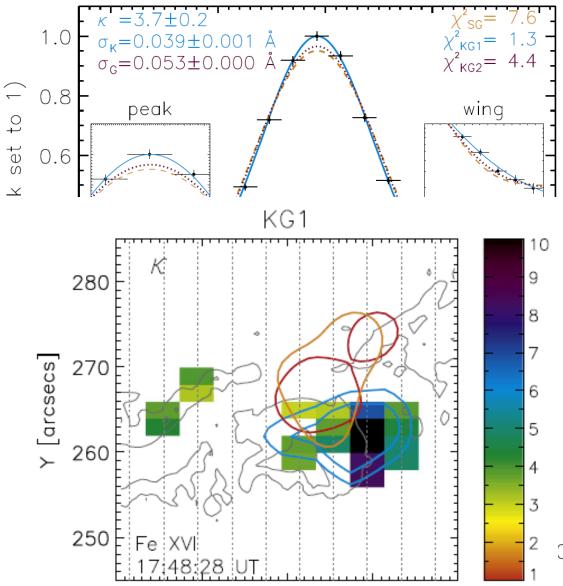
- For TR lines, ion abundance peaks are shifted to lower T
- Consequences of high-energy tail: strongly enhanced ionization
- Recombination not so strongly enhanced





### The *k*-Profiles in *Hinode*/EIS

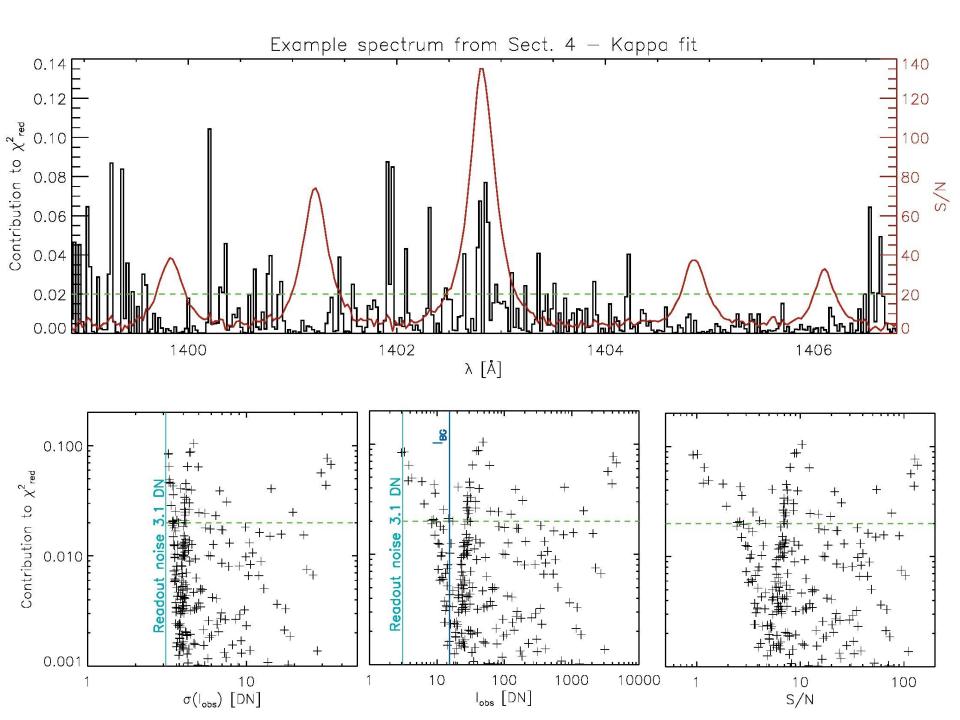
Fe XXIII

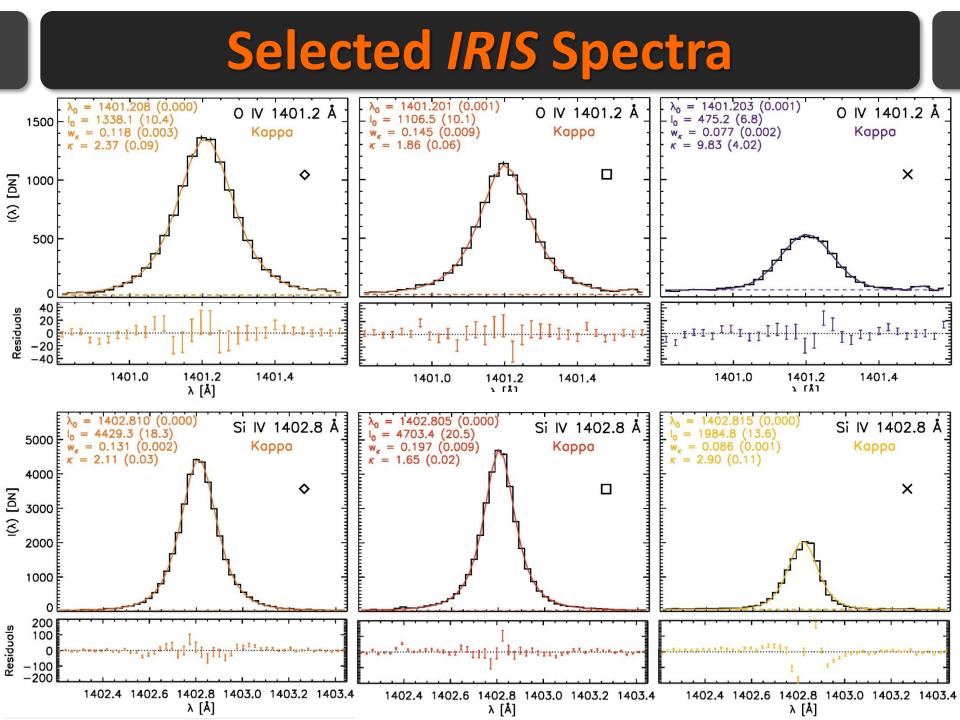


$$\mathcal{W}(\lambda) = \mathcal{G}(\lambda) * \mathcal{K}(\lambda) = A[0] + A[1]$$
$$\times \sum_{\lambda'} \exp\left(-\frac{(\lambda' - A[2])^2}{2\sigma_I^2}\right)$$
$$\times \left(1 + \frac{(\lambda - \lambda' - A[2])^2}{2A[3]^2 A[4]}\right)^{-A[4] + 1}$$

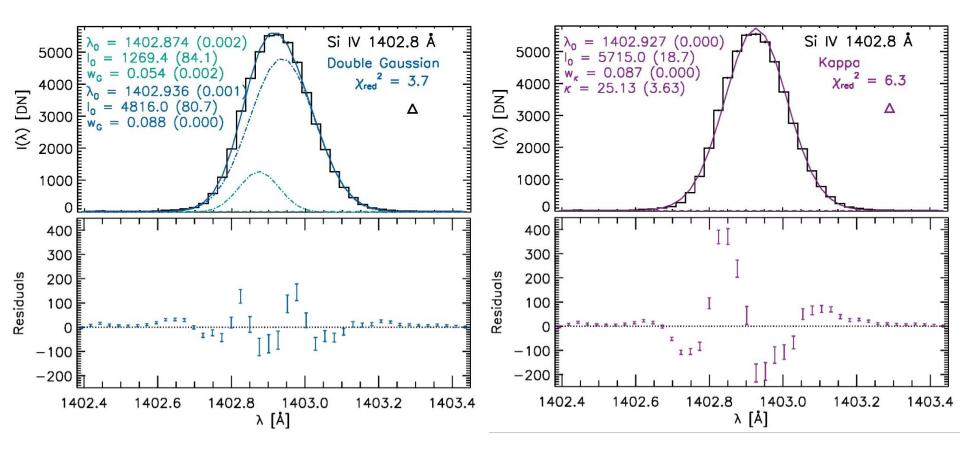
Jeffrey et al. (2016), A&A, 590, A99 Jeffrey et al. (2017), ApJ, 836, 35

- Non-Maxwellian fitting of EIS flare lines
  - **Typically find**  $\kappa \approx 2 3$
- Convolution with
   an instrumental profile,
   taken to be Gaussian





#### **Multi-Component Si IV?**



# Is the SI IV optically thick?

The optical thickness is given by (e.g., Buchlin & Vial 2009, A&A, 503, 559):

$$\tau(\lambda) = \tau_0(\lambda_0) \Phi(\lambda) = \frac{\lambda_0^4 A_{ij} \Phi(\lambda)}{4\pi^{3/2} c \Delta \lambda_{\rm D}} \frac{N({\rm Si}^{+3})}{N({\rm Si})} A({\rm Si}) \frac{N_{\rm H}}{N_{\rm e}} \langle N_{\rm e} \rangle \Delta s$$

For Maxwellian and thermal width, we get

$$\tau_0 \approx 0.26 f \frac{\langle N_{\rm e} \rangle}{10^{10} \,\mathrm{cm}^{-3}}$$

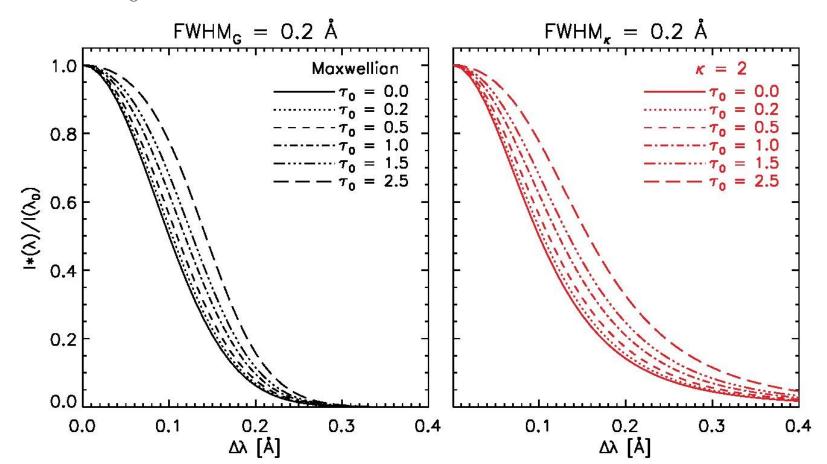
- For κ = 2, the numerical factor is about 1.5 (due to lower thermal width and higher N(Si<sup>+3</sup>) / N(Si)
- For the *observed* width and a Maxwellian, we get

$$\tau_0 \approx 0.02 f \frac{\langle N_{\rm e} \rangle}{10^{10} \,\mathrm{cm}^{-3}}$$

For κ = 2, the numerical factor is about 0.06

### Is the SI IV optically thick?

• If the line is optically thick, then the profile should be (for *S* = const.)  $I^*(\lambda) = \int_{0}^{\tau(\lambda)} S_{\lambda} \exp(-t_{\lambda}) dt_{\lambda} = S_{\lambda} \left[1 - \exp(-\tau(\lambda))\right]$ 

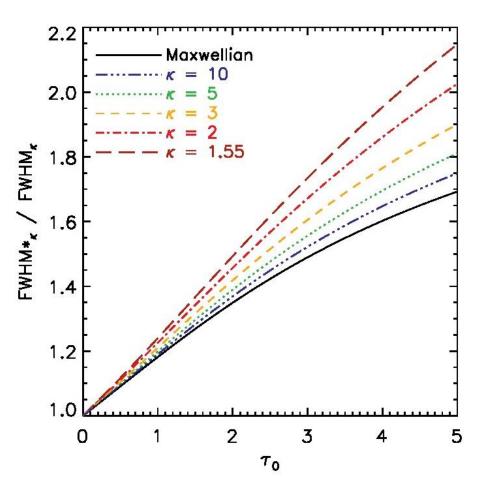


## **Multi-Component Si IV?**

The FWHM changes as

FWHM<sub>$$\kappa$$</sub><sup>\*</sup>( $\tau_0$ )<sup>2</sup> = 8( $\kappa - 3/2$ ) $w_{\kappa}^2 \left[ \left( \frac{\tau_0}{\ln(2) - \ln(\exp(-\tau_0) + 1)} \right)^{\frac{1}{\kappa}} - 1 \right]$ 

- Recall that the FWHM of the Si IV line is the same as for the O IV and S IV
- For solar conditions,
   O IV lines are always optically thin because of their small A<sub>ii</sub>
- ⇒ the Si IV is optically *thin*



#### Contents

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   Fitting with double Gaussians and a κ-distributions
   Distribution of non-Gaussian profiles
- III.Line Intensity AnalysisConsistent κ-distributions?
- IV. Leftovers Is the Si IV line optically thick?